

0.8Ω, Low Ron, Dual SPDT Analog Switch with Negative Rail Capability

FEATURES

- Low ON-State Resistance:0.8Ω (TYP)
- Supply Range: +2.5V to +5.5V
- Negative Signal Swing Capability:
 -2V to V₄
- Break-Before-Make Switching
- Fast Switching Times
- 1.8V Logic Control
- Rail-to-Rail Input and Output Operation
- Extended Industrial Temperature Range: -40°C to +85°C
- Available in Green QFN-1.4x1.8-10L Package

DESCRIPTION

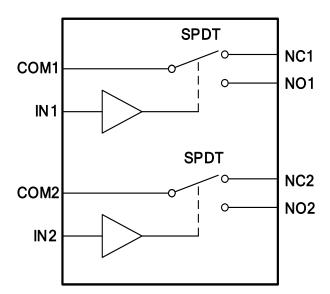
The RS2118 is a bidirectional, 2-channel single-pole double-throw (SPDT) analog switch that is designed to operate from 2.5V to 5.5V. The device features negative signal capability that allows signals below ground to pass through the switch without distortion.

The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications This device is available packaged in QFN-1.4x1.8-10L.

Functional Block Diagram

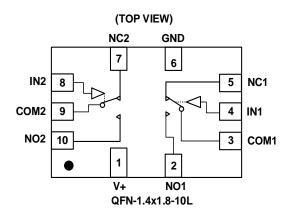
APPLICATIONS

- Wearable Devices
- Battery-Operated Equipment
- Portable Instrumentation
- Cell Phones
- Automation Test Equipment
- Relay Replacement





PIN CONFIGURATIONS



PIN DESCRIPTION

NAME	PIN	FUNCTION			
V+	1	Power Supply			
NO1, NO2	2,10	Normally-Open Terminal			
COM1, COM2	3,9	Common Terminal			
IN1, IN2	4,8	Digital Control Pin			
NC1, NC2	5,7	Normally-Closed Terminal			
GND	6	Ground			

NOTE: NOX, NCX and COMX terminals may be an input or output.

FUNCTION TABLE

LOGIC	NO	NC
0	OFF	ON
1	ON	OFF

NOTE: Switches shown for logic "0" input.



ABSOLUTE MAXIMUM RATINGS (1)

V+, IN to GND	0.3V to 6.0V
Analog Voltage Range (2)	2.0 to (V+) + 0.3V
Digital Voltage Range (2)	0.3 to (V+) + 0.3V
Continuous Current NO, NC, or COM	±250mA
Peak Current NO, NC, or COM	±350mA
Storage Temperature	−65°C to +150°C
Operating Temperature	−40°C to +85°C
QFN-1.4x1.8-10L	120°C/W
HBM	2000V
MM	200V

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3V beyond the supply rails should be current-limited to 10mA or less.



ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

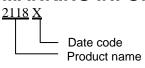
PACKAGE/ORDERING INFORMATION

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING	PACKAGE OPTION	
RS2118	RS2118YUTQK10	-40°C ~+85°C	QFN-1.4x1.8-10L	2118X	Tape and Reel,4000	

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NOTE: X = Date Code

MARKING INFORMATION





ELECTRICAL CHARACTERISTICS

V+ = 5.0 V, $T_A = -40 ^{\circ}\text{C}$ to $85 ^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	CONDITIONS	V+	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH								
Analog Signal Range	Vno, Vnc, Vcom	2.5V ≤V+≤3.5V		FULL	-2.0		V+	V
		3.5V ≤V+≤5.5V		FULL	(V+)-5.5		V+	
	Ron	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_{+},$ $I_{COM} = -10\text{mA}, \text{ Switch ON},$	5V	+25°C		0.8	1.1	Ω
On-Resistance				FULL			1.3	Ω
Oll-Inesistance	NON	See Figure 1	3.3V	+25°C		1.3	1.8	Ω
			0.0 V	FULL			2	Ω
			5V	+25°C		0.15	0.25	Ω
On-Resistance Match	ΔR_ON	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_{+},$	30	FULL			0.3	Ω
Between Channels	ween Channels ARON ICOM = -10mA, SWITCH ON, See Figure 1 3.3V	I _{COM} = -10mA, Switch ON, See Figure 1	2.21/	+25°C		0.15	0.25	Ω
		3.30	FULL			0.3	Ω	
	RFLAT(ON)	$0 \le (V_{NO} \text{ or } V_{NC}) \le V+$, $I_{COM} = -10\text{mA}$, Switch ON, See Figure 1	5 \/	+25°C		0.15	0.25	Ω
On Desistance Flatness			5V	FULL			0.3	Ω
On-Resistance Flatness			0.01/	+25°C		0.4	0.6	Ω
			3.3V	FULL			0.7	Ω
NC, NO OFF Leakage Current	INC(OFF), INO(OFF)	V _{NO} or V _{NC} = 0.3V, V+/2 V _{COM} = V+/2, 0.3V See Figure 2	2.5V to 5.5V	FULL			1	μΑ
NC, NO, COM ON Leakage Current	Inc(on), Ino(on), Icom(on)	V _{NO} or V _{NC} = 0.3V, Open V _{COM} = Open, 0.3V See Figure 3	2.5V to 5.5V	FULL			1	μΑ
DIGITAL CONTROL INP	UTS ⁽¹⁾			•				
	.,,		5V	FULL	1.5			٧
Input High Voltage	Vinh		3.3V	FULL	1.3			V
	Vinl		5V	FULL			0.5	V
Input Low Voltage			3.3V	FULL			0.4	V
Input Leakage Current	lin	Vin = Vio or 0	2.5V to 5.5V	FULL			1	μΑ

⁽¹⁾ All unused digital inputs of the device must be held at Vio or GND to ensure proper device operation.

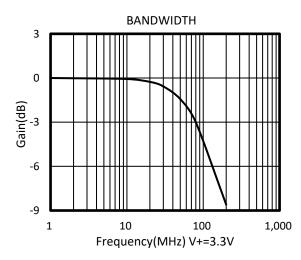


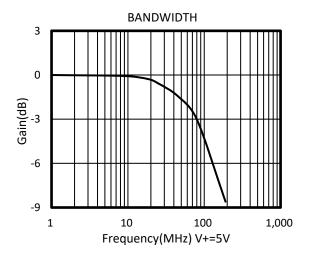
ELECTRICAL CHARACTERISTICS (continued) V+ = 5.0 V, TEMP= -40°C to 85°C (unless otherwise noted))

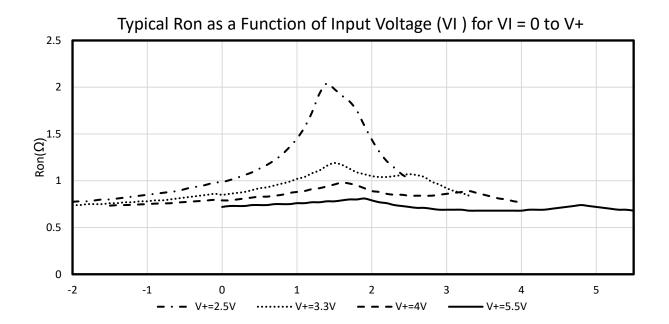
PARAMETER	SYMBOL	CONDITIONS		V+	TEMP	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTER	RISTICS								
Turna On Time	4	$V_{COM} = V+, R_L = 300\Omega, C_L = 3$		5V	.05°0		15		
Turn-On Time	ton	See Figure 5	•	3.3V	+25°C		25		ns
Turn-Off Time	t	$V_{COM} = V+, R_L = 300\Omega,$, C _L = 35pF,	5V	.05%0		10		
Turn-Oil Time	t off	See Figure 5		3.3V	+25°C		15		ns
Break-Before-Make	4	V _{NO1} = V _{NC1} = V _{NO2} = V	V _{NO1} = V _{NC1} = V _{NO2} = V _{NC2} = V+/2.		0500		5		ns
Time Delay	TRRM TRRM		See Figure 6	3.3V	+25°C		10		
Oh anna Inia atian		V_G =GND, R_G =0 Ω , C_L =1.0nF, See Figure 10		5V	+25°C		80		рС
Charge Injection	Q			3.3V	+25°C	;	74		
		$R_L = 50\Omega$, Switch OFF,	f = 1MHz		+25°C		-70		dB
Off Isolation	Oiso	Olso See Figure 8	f = 10MHz		+25°C		-50		dB
-3dB Bandwidth	BW	Switch ON, R _L = 50Ω See Figure 7			+25°C		80		MHz
Channel-to-Channel		Signal=0dBm, R _L =	f = 1MHz		+25°C		-72		dB
Crosstalk	X _{TALK}	50Ω , C _L = 5pF, See Figure 9	f = 10MHz		+25°C		-52		dB
NC, NO OFF Capacitance	CNC(OFF), CNO(OFF)	V _{NC} or V _{NO} =V+/2 or GND, Switch OFF See Figure 4			+25°C		40		pF
NC, NO, COM ON Capacitance	CNC(ON), CNO(ON), CCOM(ON)	V _{NC} or V _{NO} =V+/2 or GND, Switch ON See Figure 4			+25°C		85		pF
POWER REQUIREMENT	тѕ								
Power Supply Range	V+				FULL	2.5		5.5	V
Power Supply Current	I+	V _{IN} = GND or V ₊		5.5V	FULL			1	μΑ



TYPICAL CHARACTERISTICS









Parameter Measurement Information

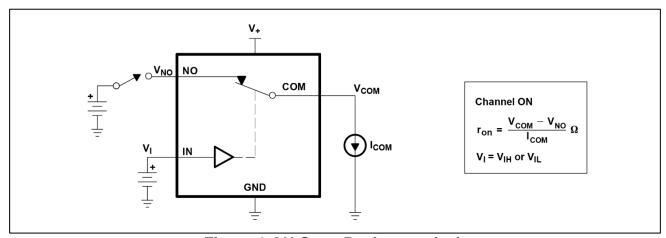


Figure 1.ON-State Resistance (ron)

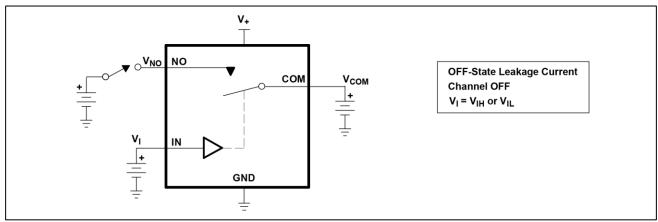


Figure 2.OFF-State Leakage Current (ICOM(OFF), INO(OFF))

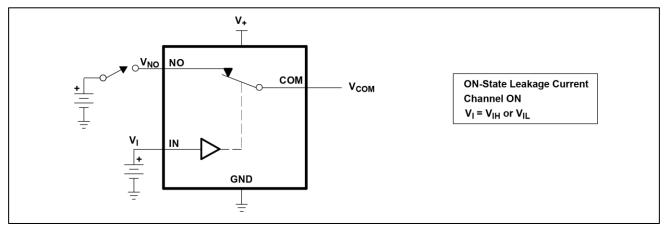


Figure 3. ON-State Leakage Current (Icom(on), Ino(on))



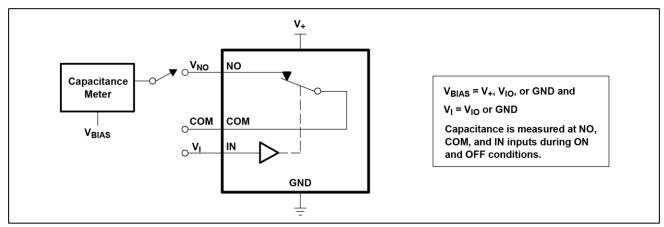


Figure 4. Capacitance (CI, CCOM(OFF), CCOM(ON), CNO(OFF), CNO(ON))

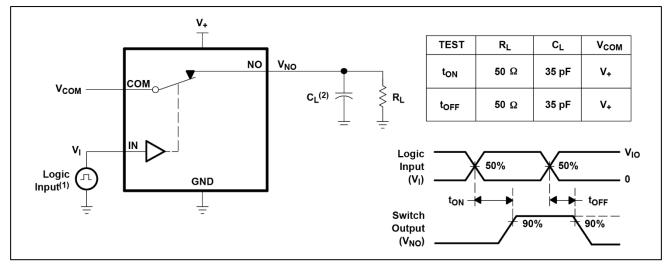


Figure 5.Turn-On (ton) and Turn-Off Time (toff)

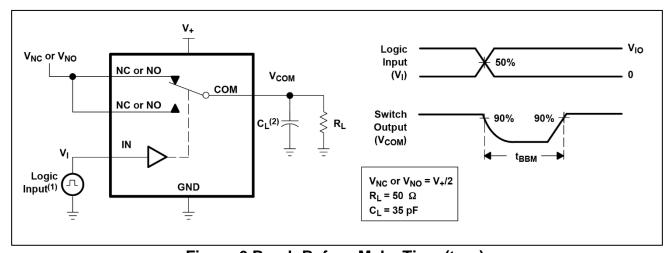


Figure 6.Break-Before-Make Time (tbbm)

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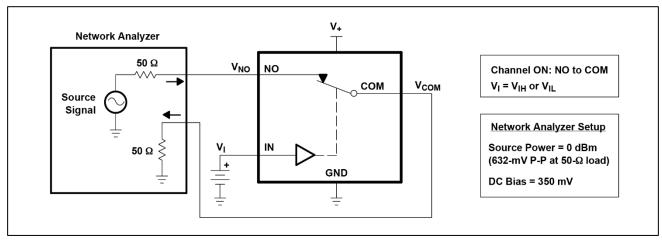


Figure 7. Bandwidth (BW)

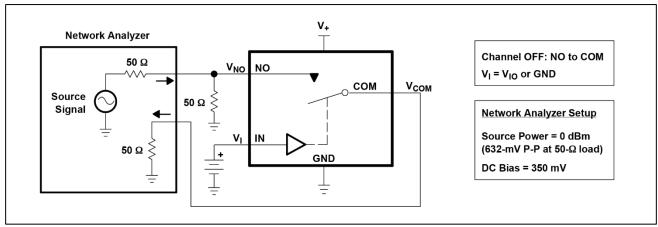


Figure 8.OFF Isolation (O_{ISO})

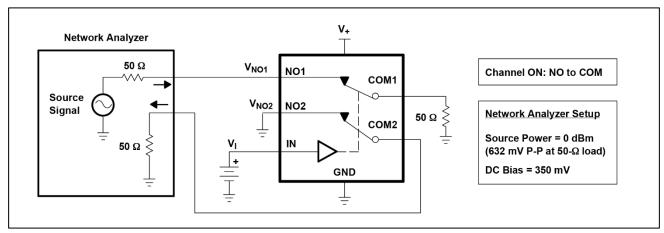


Figure 9. Crosstalk (XTALK)

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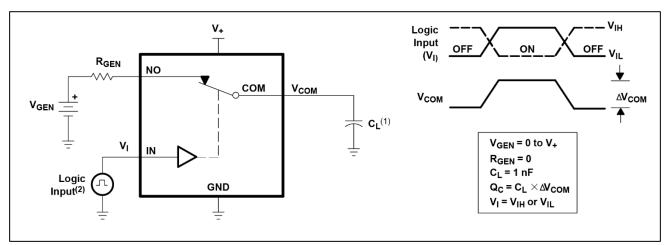


Figure 10. Charge Injection (Qc)

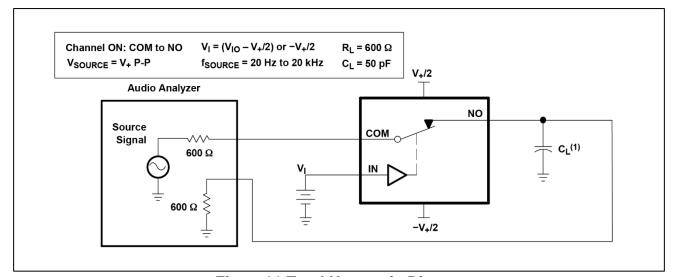


Figure11.Total Harmonic Distort



TYPICAL APPLICATION

Ensure that the device is powered up with a supply voltage on VCC before a voltage can be applied to the signal paths NC and NO. All unused digital inputs of the device must be held at VCC or GND to ensure proper device operation. Tie the digitally controlled inputs select pins IN1 and IN2 to VCC or GND to avoid unwanted switch states that could result if the logic control pins are left floating.

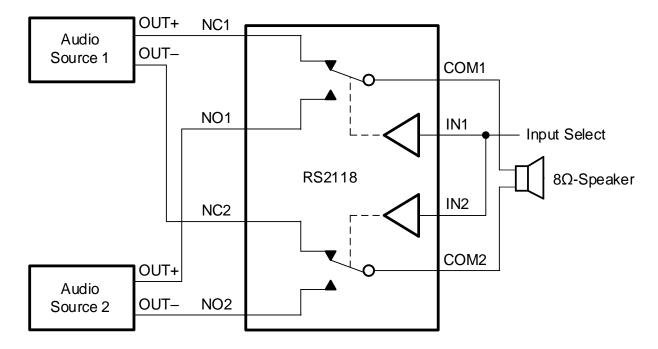
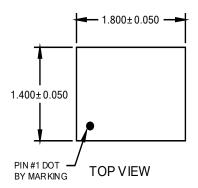
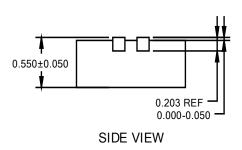


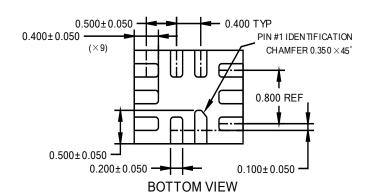
Figure 12. Typical Application Schematic

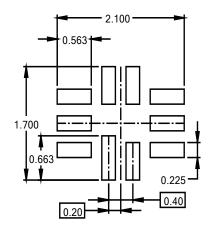


PACKAGE OUTLINE DIMENSIONS QFN-1.4x1.8-10L









RECOMMENDED LAND PATTERN